

1SS86

Silicon Schottky Barrier Diode for UHF TV Tuner Mixer

REJ03G0614-0300

(Previous: ADE-208-186B)

Rev.3.00

May 09, 2005

Features

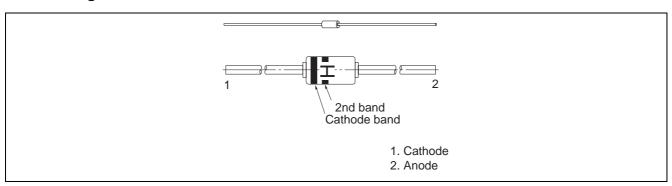
• Low capacitance. (C = 0.85 pF max)

• High reliability with glass seal.

Ordering Information

Type No.	Cathode band	2nd band	Mark	Package Name	Package Code (Previous Code)
1SS86	White	White	Н	DO-35	GRZZ0002ZB-A (DO-35)
					(DO-35)

Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Reverse voltage	V _R	3	V
Average rectified current	I ₀	30	mA
Power dissipation	Pd	150	mW
Junction temperature	Tj	100	°C
Storage temperature	Tstg	-55 to +100	°C

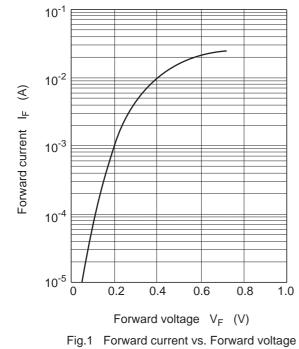
Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward current	I _F	8	_	_	mA	$V_F = 0.5 \text{ V}$
Reverse current	I _R	_	_	50	μΑ	V _R = 0.5 V
Reverse voltage	V_R	3.0	_	_	V	I _R = 1 mA
Capacitance	С	_	_	0.85	pF	V _R = 0.5 V, f = 1 MHz
ESD-Capability *	_	30	_	_	V	$C = 200 \text{ pF}, R = 0 \Omega$, Both forward and reverse direction 1 pulse.

Note: Failure criterion ; $I_R > 50 \mu A$ at $V_R = 0.5 V$

Main Characteristic



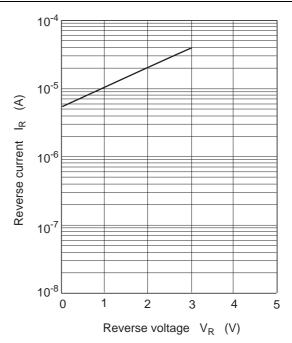
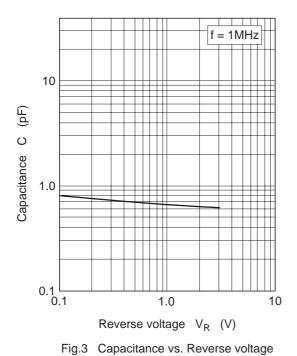
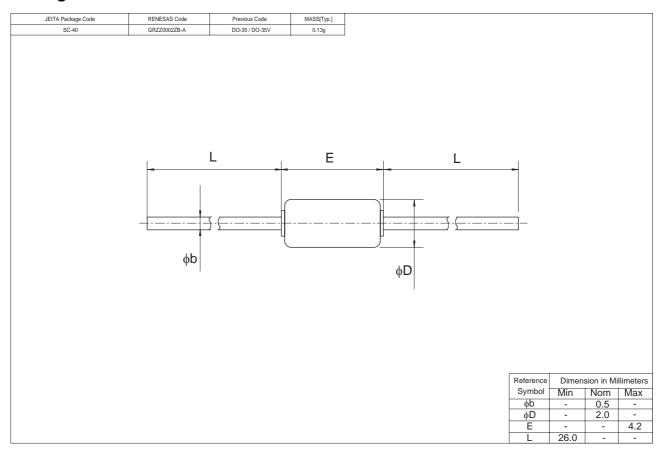


Fig.2 Reverse current vs. Reverse voltage



Package Dimensions



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